NSN 5961-00-981-3275

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-981-3275 **Inclosure Material:** Metal **Overall Length:** 0.250 inches **Overall Diameter:** 0.370 inches **Component Name And Quantity:** 2 transistor **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 100.0 collector to base voltage, dc all transistor and 60.0 collector to emitter voltage, dc all transistor **Power Rating Per Characteristic:** 0.6 watts small-signal input power, common-collector all transistor **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** All transistor junction pattern arrangement: npn **Terminal Type And Quantity:** 6 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0